




SI7842DP-T1-GE3

Fabricant Numéro d'article:	SI7842DP-T1-GE3
Fabricant / marque	Electro-Films (EFI) / Vishay
Partie de la description:	MOSFET 2N-CH 30V 6.3A PPAK SO-8
Feuilles de données:	SI7842DP-T1-GE3.pdf
État sans plomb / État RoHS:	 Sans plomb / conforme à la directive RoHS
Etat du stock:	Nouvel original, stock 2600 disponible.
Bateau de:	Hong Kong
Manière d'expédition:	DHL/Fedex/TNT/UPS

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SI7842DP-T1-GE3 100% Nouveaux originaux 2600 en stock, Trouver SI7842DP-T1-GE3 Prix, Stock, Fiche technique chez IC Components Ltd en ligne, achetez SI7842DP-T1-GE3 Electro-Films (EFI) / Vishay avec garantie. 100% de garantie de confiance. RFQ SI7842DP-T1-GE3: Info@IC-Components.com



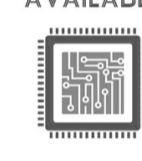




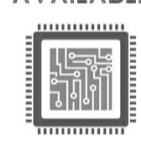
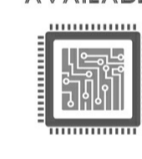
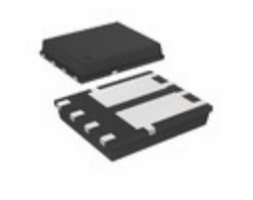

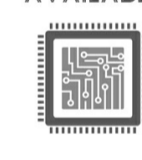

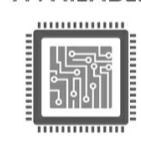
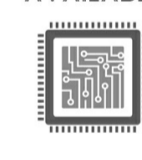


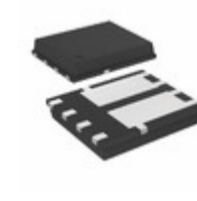

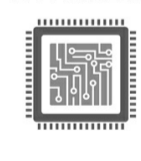


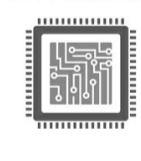



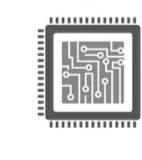


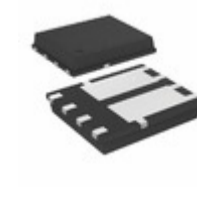
Les spécifications de SI7842DP-T1-GE3

Numéro d'article	SI7842DP-T1-GE3	Fabricant / marque	Electro-Films (EFI) / Vishay
Séries	LITTLE FOOT®	Niveau de sensibilité à l'humidité (MSL)	1 (Unlimited)
Numéro de pièce de base	SI7842	Package / Boîte	PowerPAK® SO-8 Dual
Emballage	Tape & Reel (TR)	Type de montage	Surface Mount
Package composant fournisseur	PowerPAK® SO-8 Dual	Température de fonctionnement	-55 °C ~ 150 °C (TJ)
Description détaillée	Mosfet Array 2 N-Channel (Dual) 30V 6.3A 1.4W Surface Mount PowerPAK® SO-8 Dual	Puissance - Max	1.4W
type de FET	2 N-Channel (Dual)	Fonction FET	Logic Level Gate
Tension drain-source (Vdss)	30V	Courant - Drainage continu (Id) à 25 ° C	6.3A
Rds On (Max) @ Id, Vgs	22 mOhm @ 7.5A, 10V	Vgs (th) (Max) @ Id	2.4V @ 250µA
Charge de la porte (Qg) (Max) @ Vgs	20nC @ 10V	Capacité d'entrée (Ciss) (Max) @ Vds	-
Autres noms	SI7842DP-T1-GE3TR SI7842DPT1GE3	Quantité en stock	2600 pcs Stock
Catégorie	Produits semi-conducteurs discrets > Transistors - FET, MOSFET - tableaux	La description	MOSFET 2N-CH 30V 6.3A PPAK SO-8
État sans plomb / État RoHS	Sans plomb / conforme à la directive RoHS		

Mots-clés associés à SI7842DP-T1-GE3

Electro-Films (EFI) / Vishay SI7842DP-T1-GE3	Partie SI7842DP-T1-GE3	Prix SI7842DP-T1-GE3	Distributeur SI7842DP-T1-GE3
SI7842DP-T1-GE3 technique	Action SI7842DP-T1-GE3	SI7842DP-T1-GE3 Inventaire	SI7842DP-T1-GE3 Fournisseur
Commande en ligne SI7842DP-T1-GE3	SI7842DP-T1-GE3 Enquête	Image SI7842DP-T1-GE3	SI7842DP-T1-GE3 Image
SI7842DP-T1-GE3 pdf	Fiche technique SI7842DP-T1-GE3	Fiche technique SI7842DP-T1-GE3	SI7842DP-T1-GE3 pdf datasheet
Téléchargez la fiche technique SI7842DP-T1-GE3	Electro-Films (EFI) / Vishay Fabricant	Electro-Films (EFI) / Vishay SI7842DP-T1-GE3	Electro-Films (EFI) / Vishay SI7842DP-T1-GE3
Vishay Electro-Films SI7842DP-T1-GE3	Phoenix Passive Components / Vishay SI7842DP-T1-GE3		

Vous pouvez également être intéressé par:

 <p>SI7848BDP-T1-E3 La description: MOSFET N-CH 40V 47A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 13800 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7840DP-T1 La description: SI7840DP-T1 VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 48000 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7840DP La description: SI7840DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 56500 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7848DP-T1-E3 La description: MOSFET N-CH 40V 10.4A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 4000 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7848BDP-T1-GE3 La description: MOSFET N-CH 40V 47A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 5100 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7840BDP La description: SI7840BDP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 2100 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7846SAC La description: SI7846SAC VISHAY QFN Fabricants: Vishay Precision Group En stock: Nouvel original, stock 2100 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7840BDP La description: SI7840BDP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 2100 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7848BDP La description: SI7848BDP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 100 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7842DP-T1-GE3 La description: MOSFET 2N-CH 30V 6.3A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 68300 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7846DP-T1-GE3 La description: MOSFET N-CH 150V 4A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 2900 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7844DP La description: SI7844DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 7300 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7818DN-T1-E3 La description: MOSFET N-CH 150V 2.2A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 23000 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7820DN La description: SI7820DN SI QFN1212-8 Fabricants: SI En stock: Nouvel original, stock 300 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7842DP La description: SI7842DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 2800 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7820DN-T1-GE3 La description: MOSFET N-CH 200V 1.7A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 23000 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7846DP-TI La description: SI7846DP-TI VISHAY QFN Fabricants: Vishay Precision Group En stock: Nouvel original, stock 1200 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7844DP-T1-E3 La description: MOSFET 2N-CH 30V 6.4A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 62800 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7846DP-T1-E3 La description: MOSFET N-CH 150V 4A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 21000 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7840DP-T1-GE3.3 La description: SI7840DP-T1-GE3.3 VIS QFN Fabricants: VIS En stock: Nouvel original, stock 52200 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7844DP-T1 La description: SI7844DP-T1 VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 3000 disponible. Citation: <input type="text" value="RFQ"/></p>
 <p>SI7848BDP-T1 La description: SI7848BDP-T1 VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 100 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7840 La description: SI7840 SILICONIX QFN Fabricants: SILICONIX En stock: Nouvel original, stock 700 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7820DN-T1-E3 La description: MOSFET N-CH 200V 1.7A 1212-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 3300 disponible. Citation: <input type="text" value="RFQ"/></p>
<p>IMAGE NOT AVAILABLE</p>  <p>SI7848DP La description: SI7848DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 2400 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7840BDP-T1-E3 La description: MOSFET N-CH 30V 11A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 26000 disponible. Citation: <input type="text" value="RFQ"/></p>	<p>IMAGE NOT AVAILABLE</p>  <p>SI7840DP-T1-GE3 La description: SI7840DP-T1-GE3 VB QFN8 Fabricants: VB En stock: Nouvel original, stock 17600 disponible. Citation: <input type="text" value="RFQ"/></p>
<p>IMAGE NOT AVAILABLE</p>  <p>SI7846DP La description: SI7846DP SI QFN-8 Fabricants: SI En stock: Nouvel original, stock 8000 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7840DP-T1-E3 La description: SI7840DP-T1-E3 VISHAY QFN8 Fabricants: Vishay Precision Group En stock: Nouvel original, stock 26000 disponible. Citation: <input type="text" value="RFQ"/></p>	 <p>SI7844DP-T1-GE3 La description: MOSFET 2N-CH 30V 6.4A PPAK SO-8 Fabricants: Electro-Films (EFI) / Vishay En stock: Nouvel original, stock 6000 disponible. Citation: <input type="text" value="RFQ"/></p>



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